

BY251-BY255

Technical Data Data Sheet N0552, Rev. A Green Products

BY251 THRU BY255

GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 200 to 1300 Volts Forward Current - 3.0 Ampere

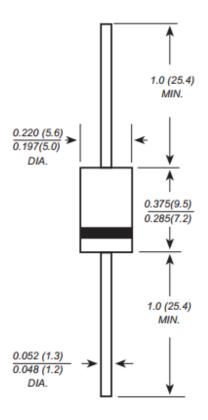
FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed: 260 °C /10 seconds,0.375"(9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

- Case: DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight:0.04 ounce, 1.10 grams

MECHANICAL DIMENSIONS: In Inches/mm



DO-201AD

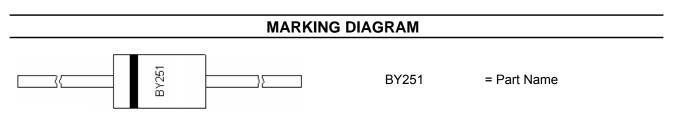
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Cautions: Molding resin

Epoxy resin UL:94V-0

ORDERING INFORMATION

Device	Package	Shipping
BY251-BY255	DO-201AD	1250pcs / tape
	(Pb-Free)	123000037 tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	BY251	BY252	BY253	BY254	BY255	Unit
Maximum repetitive peak reverse voltage Maximum DC blocking voltage	$V_{RRM} \ V_{DC}$	200	400	600	800	1300	V
Maximum RMS voltage	V_{RMS}	140	280	420	560	910	V
Maximum average forward rectified current $0.375"(9.5mm)$ lead length at @T _A = 75°C	I _(AV) 3.0			А			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150					А
Maximum instantaneous forward voltage at 3.0A	V _F	1.1					V
Maximum DC reverse current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I _R	10.0 500					μA
Typical Junction Capacitance (Note 1)	CJ	30.0					pF
Typical Thermal Resistance (Note 2)	$R_{ extsf{ heta}JA}$	20.0					°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175					°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375"(9.5mm)lead length, P.C.B. mounted

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RATINGS AND CHARACTERISTIC CURVES BY251 THRU BY255

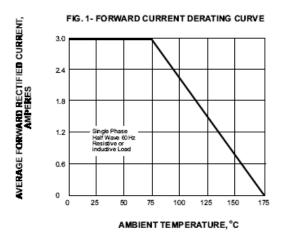


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

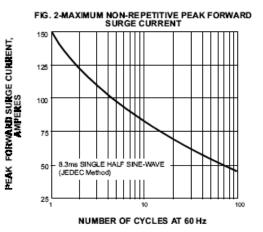
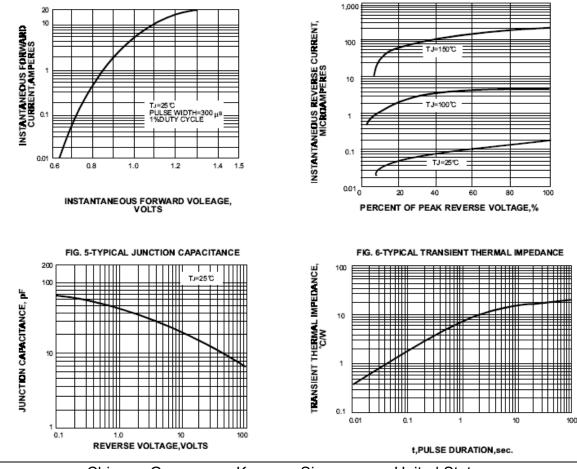


FIG. 4-TYPICAL REVERSE CHARACTERISTICS



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